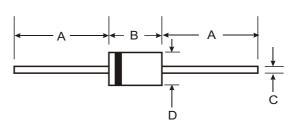


# SB120 - SB160

### 1.0A SCHOTTKY BARRIER RECTIFIER

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- · Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 40A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material UL Flammability Classification 94V-0



## **Mechanical Data**

Case: Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: Cathode Band

Weight: 0.3 grams (approx.)

Mounting Position: Any

Marking: Type Number

| DO-41 Plastic        |       |       |  |  |  |  |
|----------------------|-------|-------|--|--|--|--|
| Dim                  | Min   | Max   |  |  |  |  |
| A                    | 25.40 | _     |  |  |  |  |
| В                    | 4.06  | 5.21  |  |  |  |  |
| С                    | 0.71  | 0.864 |  |  |  |  |
| D                    | 2.00  | 2.72  |  |  |  |  |
| All Dimensions in mm |       |       |  |  |  |  |

## Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

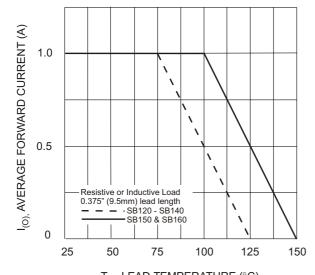
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol   | SB120                   | SB130 | SB140 | SB150 | SB160 | Unit |
|---|--|-------------------------|-------|-------|-------|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 20                      | 30    | 40    | 50    | 60    | V    |
| RMS Reverse Voltage   | V <sub>R(RMS)</sub>                                    | 14                      | 21    | 28    | 35    | 42    | V    |
| Average Rectified Output Current (Note 1) (See Figure 1)  |  | 1.0                     |       |       |       |       | А    |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>single half sine-wave superimposed on rated load<br>(JEDEC Method) |  | 40                      |       |       |       |       | А    |
| Forward Voltage (Note 2) @ I <sub>F</sub> = 1.0A  | V <sub>FM</sub>  | 0.50 0.70               |       |       | 70    | V     |      |
| Peak Reverse Current @ T <sub>A</sub> = 25°C  |  | 0.5                     |       |       |       | mA    |      |
| at Rated DC Blocking Voltage (Note 2) @ T <sub>A</sub> = 100°C  | I <sub>RM</sub>  |                         | 10    | 5.0   |       | .0    | TIIA |
| Typical Thermal Resistance Junction to Lead (Note 1)  |  | 15                      |       |       |       |       | °C/W |
| Typical Thermal Resistance Junction to Ambient  |  | 50                      |       |       |       |       | °C/W |
| Operating Temperature Range   |  | -65 to +125 -65 to +150 |       |       | +150  | ∘c    |      |
| Storage Temperature Range   |  | -65 to +150             |       |       |       |       |      |

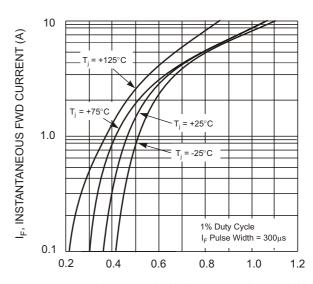
Notes: 1. Measured at ambient temperature at a distance of 9.5mm from the case.

2. Short duration test pulse used to minimize self-heating effect.

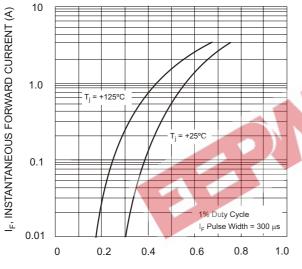




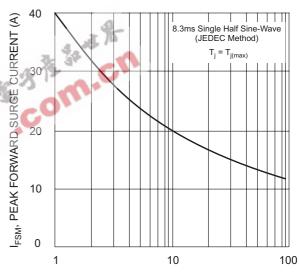
 ${\rm T_L},\ {\rm LEAD\ TEMPERATURE\ (^{\circ}C)}$  Fig. 1 Forward Current Derating Curve



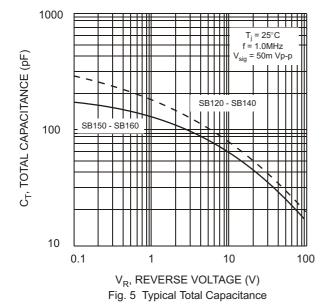
 $\rm V_F$ , INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics - SB120 thru SB140

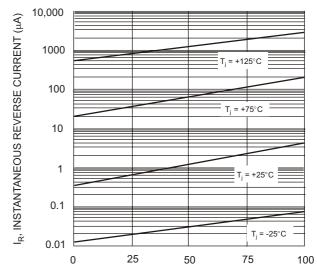


 $\rm V_F$ , INSTANTANEOUS FWD VOLTAGE (V) Fig. 3 Typ. Forward Characteristics - SB150 thru SB160



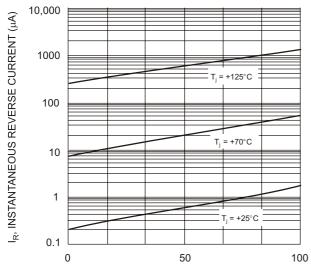
NUMBER OF CYCLES AT 60 Hz Fig. 4 Max Non-Repetitive Peak Fwd Surge Current





PERCENTAGE OF PEAK REVERSE VOLTAGE (%)
Fig. 6 Typical Reverse Characteristics, SB120 thru SB140





PERCENTAGE OF PEAK REVERSE VOLTAGE (%)
Fig. 7 Typical Reverse Characteristics, SB150 thru SB160

